NSN 5961-01-050-3636

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Inclosure Material:
Metal
Overall Length:
Between 1.832 inches and 1.872 inches
Overall Height:
Between 0.250 inches and 0.450 inches
Overall Width:
1.050 inches
End Application:
E-3a
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
T0-3
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.00 breakdown voltage, collector-to-emitter, base open
Current Rating Per Characteristic:
30.00 amperes source cutoff current and 1.00 milliamperes zero-gate-voltage source current preset
Power Rating Per Characteristic:
200.0 watts small-signal input power, common-collector absolute
Transfer Ratio:
15.0 static forward current transfer ratio, common-emitter and 60.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Terminal Type And Quantity:
1 case and 2 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

No

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